

Investor Presentation

January 2021

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This presentation and the accompanying oral presentation contain "forward-looking statements" that involve risks, uncertainties and assumptions. If the risks or uncertainties ever materialize or the assumptions prove incorrect, our results may differ materially from those expressed or implied by such forwardlooking statements. All statements relating to events or results that may occur in the future are forward looking statements, including, but not limited to: any projections of addressable market size, market trends and market opportunities, customer growth, design win growth, product availability or technology developments; any statements suggesting future trends for our business; any statements regarding our plans, strategies or objectives with respect to future operations; and any statements regarding future economic conditions. These statements are based on estimates and information available to us at the time of this presentation and are not guarantees of future performance. Actual results could differ materially from our current expectations as a result of many factors, including, but not limited to: market adoption of our products and solutions may be different than we expect; our rate of growth; our ability to predict customer demand for our existing and future products and to secure adequate manufacturing capacity; our ability to manage our growth; our ability to hire, retain and motivate employees; the effects of competition, including price competition; technological, regulatory and legal developments; developments in the economy and financial markets; and the duration and severity of the COVID-19 pandemic and its effects on our business, financial condition, results of operations and cash flows. These factors, together with those set forth under the caption "Risk Factors" in our most recent Quarterly Report on Form 10-Q filed with the Securities and Exchange Commission ("SEC") on November 5, 2020 and in our other filings with the SEC, may cause our actual results, performance or achievements to differ materially and adversely from those anticipated or implied by our forward-looking statements. You should not rely upon forward-looking statements as predictions of future events. Although our management believes that the expectations reflected in our forward-looking statements are reasonable, we cannot guarantee that the future results, levels of activity, performance or events and circumstances described in the forward-looking statements will be achieved or occur. Moreover, neither we, nor any other person, assume responsibility for the accuracy and completeness of the forward-looking statements. Any forward-looking statements made by us speak only as of the date on which they are made, and we undertake no obligation to publicly update any forward-looking statements for any reason after the date of this presentation to conform these statements to actual results or to changes in our expectations, except as required by law.



Company Overview

Leading Provider of Specialty Memory Technology and Products to Mission-Critical Applications from the **Data Center** to **Industrial and IoT End Point** applications

Headquarters Chandler, AZ

Established 2008

Listed NASDAQ: MRAM

Segment Semiconductor Memory

Total 2019 Revenue \$37.5M

Diversified Customer Base

1,300+

Across multiple markets

In Production over 12 years

120M+

MRAM Units shipped

Strong IP Portfolio

650+

Patents and applications WW

Focused on differentiated value and long-term growth in stable and growing markets



3Q 2020 Highlights And 4Q 2020 Outlook

- Delivered positive cash flow from operations for first time in company history
- Achieved \$5M annual operating expense reduction one quarter ahead of plan
- Achieved another quarter of record design wins
- Started production shipments to second 1Gb STT-MRAM customer, for use in a persistent memory card application for data center
- Completed production rollout of expanded Toggle product portfolio
- Updated 4Q revenue guidance as of December 15th, 2020, of \$10.1M to \$10.5M
 - Compares to initial 4Q guidance of \$10.1M-\$10.9M in revenue and GAAP net loss of (\$0.10) to (\$0.04) per share, which reflects expected stock-based compensation expense of approximately \$0.9 million



Only MRAM Demonstrates The Promise of Universal Memory

PERSISTENCE

Maintains memory contents without requiring power

PERFORMANCE

SRAM & DRAM-like performance with low latency

ENDURANCE

Superior durability supports memory workloads without sophisticated management

RELIABILITY

Best-in-class robustness designed and tested for extreme conditions





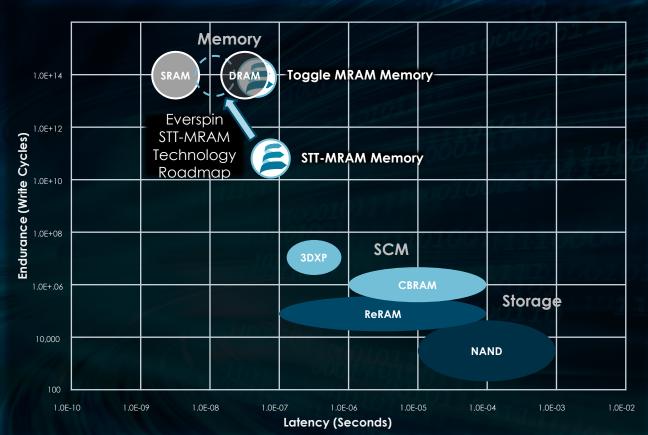




MRAM as a CPU-attached memory (like SRAM/DRAM) that brings non-volatile capability (like Flash)



MRAM Brings Native Persistence to Memory Workloads



MRAM COMBINES PERFORMANCE OF MEMORY WITH PERSISTENCE OF STORAGE

- Persistence: Months to decades of data retention without power or refresh
- Performance: Read/write similar to DRAM
- Endurance: Handles memory workloads



5G Opens A Universe of MRAM Applications

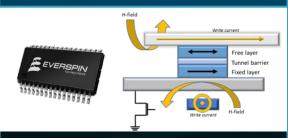
Core Edge **End Points** 27B Networked Industrial & By 2025 75% of enterprise data 175 Zettabytes of will be created and processed loT Devices by 2021 data by 2025 outside the Datacenter **Producing 79 ZB** Industrial Gaming Enterprise **Automation** Storage Smart Medical (W)) Meter (W)) Electric (W) 5G Transportation Charaina **Fabric** Persistent Enterprise Accelerator Memory Infrastructure Server RAID

5G brings unprecedented bandwidth expected to increase Industrial and IoT End Point persistent memory needs and drive lower Core latency in the Data Center



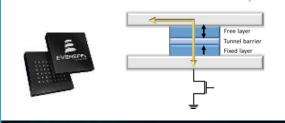
Product Portfolio Expands End Point Application Opportunity

Industrial/IoT Toggle MRAM



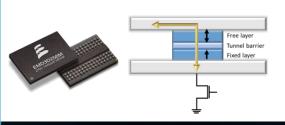
- SPI, QSPI, Parallel I/F
- 128 Kb to 32 Mb
- SRAM-like performance
- 20 years data retention
- -55C to 125C Operating Temp.
- Most robust MRAM

Industrial/IoT STT-MRAM



- SPI, QSPI, OSPI, xSPI
- 64 Mb to 256 Mb
- SRAM-like performance
- 10 years data retention
- -40C to 85C Operating Temp.
- Most affordable MRAM

Data Center STT-MRAM



- ST-DDR3, ST-DDR4 I/F
- 256 Mb to 1 Gb
- DRAM-like performance
- 3 months to 10 years DR
- 0C to 85C Operating Temp.
- Highest density MRAM

Our new product development expands the opportunity for STT to existing and new MRAM customers



MRAM in Industrial & IoT **Universal Non-Volatile Memory**

Bringing robust and simple nonvolatility to applications that need to store mission-critical data in CPU attached memory configurations





Network &

Infrastructure

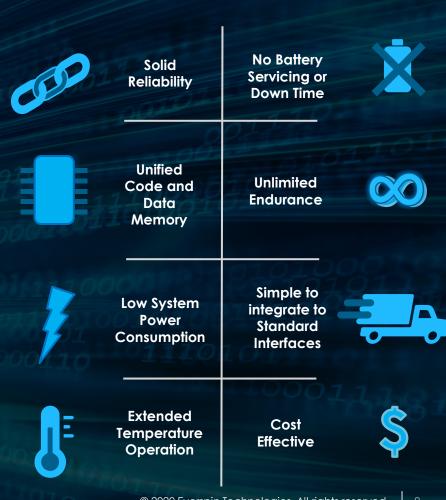








Other Industrial



MRAM in the Data Center Lowest Latency Persistent Memory

Addressing the need for assured data integrity in high performance data buffering applications with unmatched endurance and reliability



Enterprise Storage



Enterprise Server RAID



Persistent Memory



Fabric Accelerator



Solid Reliability

No Stored Energy Liability





Larger Buffer Improves Latency QOS

No Capacitor Backed RAM





Optimized
Interleave For
Sequential
Performance

Simplified
Architecture
Eliminates Power
Fail Hardenina





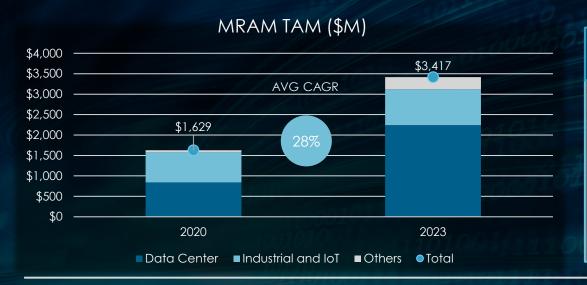
More Physical Space For Storage Capacity

Enable Higher Number of Streams





Market Potential In Data Center Core And Industrial/IoT End Points



KEY SUCCESS FACTORS

- Focus on high value segments that need higher performance and reliability
- STT-MRAM penetration in Data Center Core Applications
- Expand opportunities for MRAM with Industrial/IoT STT-MRAM
- Leverage expanded supply

CURRENT FOCUS SEGMENTS



Enterprise Storage



Enterprise Server RAID



Industrial Automation



Medical



Network & Infrastructure



Casino Gaming



Other Industrial

GROWTH OPPORTUNITIES



Persistent Memory



Fabric Accelerator



Mil/Aero



Transportation



Diversified Top-Tier Customer Base in Significant Markets



Serving some of the most demanding customers in segments with long-term stability



Everspin IP Delivers Value Through Licensing

Magnetic Sensors

Mil-Aero Toggle MRAM

Embedded STT-MRAM







Honeywell





Everspin has successfully licensed MRAM, 3D Magnetic Sensor and TMR Head Sensor (HDD) IP

The Executive Team



Executive Chairman & Interim CEO





Daniel Berenbaum

Chief Financial Officer



Sanjeev Aggarwal

VP, Technology R&D



Troy Winslow

VP, Sales & Marketing





Norm Armour

VP, Operations







Yong Kim

VP, Product Development



Proven Team With Strong Experience In Delivering Market Leading Technology



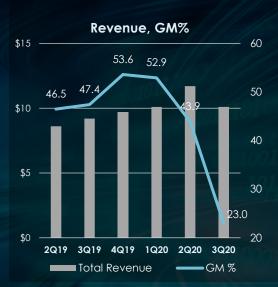




Key Financial Indicators

As of 3Q 2020

Sequential Revenue Growth With Path to Margin Improvement



Well Controlled OPEX



Moving Toward Profitability



• 3Q20 results reflect a \$1.7M non-cash charge related to excess and obsolete inventory reserve, \$0.4M accelerated depreciation, and a \$0.1M prior period cost adjustment

Everspin is focused on building a sustainable business model



Income Statement

(\$M)	1Q19	2Q19	3Q19	4Q19	1Q20	2Q20	3Q20
Revenue	\$10.0	\$8.6	\$9.2	\$9.7	\$10.1	\$11.8	\$10.1
Gross Profit	\$4.8	\$4.0	\$4.4	\$5.2	\$5.4	\$5.2	\$2.3
R&D	\$4.0	\$3.5	\$3.4	\$3.3	\$3.0	\$2.8	\$2.6
SG&A	\$5.0	\$4.1	\$4.5	\$4.1	\$3.9	\$3.5	\$3.5
Restructuring				\$0.8			
Operating Income	(\$4.2)	(\$3.6)	(\$3.6)	(\$3.0)	(\$1.6)	(\$1.1)	(\$3.7)

 ³Q20 results reflect a \$1.7M non-cash charge related to excess and obsolete inventory reserve, \$0.4M accelerated depreciation, and a \$0.1M prior period cost adjustment



Balance Sheet

(\$M)	1Q19	2Q19	3Q19	4Q19	1Q20	2Q20	3Q20
Cash & Equivalents	\$18.5	\$15.3	\$14.8	\$14.5	\$14.0	\$12.9	\$13.9
Assets	\$42.2	\$37.5	\$35.1	\$35.4	\$34.7	\$35.1	\$33.2
Debt	\$11.0	\$9.6	\$7.7	\$7.8	\$7.9	\$7.9	\$7.9
Liabilities	\$20.8	\$18.8	\$17.0	\$16.9	\$14.7	\$14.7	\$15.3
Equity	\$21.4	\$18.6	\$18.1	\$18.5	\$20.0	\$20.4	\$18.0

- Raised an aggregate of \$6.9M in net proceeds from ATM facility in 3Q19 through 1Q20 periods. ATM sales were suspended in March 2020 Refinanced debt in August 2019 and further amended credit agreement in July 2020, which delays principal payments until January 2021, significantly reducing debt service costs



Target Operating Model

	2018	2019	1Q20	2Q20	3Q20	Target Model
Revenue (\$M)	\$49.4	\$37.5	\$10.1	\$11.8	\$10.1	>20% CAGR
Gross Margin %	51.3%	48.9%	52.9%	43.9%	23.0%	>50%
R&D	48%	38%	30%	23%	25%	20%
SG&A	38%	47%	39%	30%	34%	17%
Operating Income	(35%)	(38%)	(16%)	(9%)	(37%)	>13%

^{• 2018} reflects significant one-time license revenue



^{• 3}Q20 reflects non-cash charge related to excess and obsolete inventory reserve, accelerated depreciation and a prior period cost adjustment

Key Investor Takeaways

Unique success producing high-value discrete MRAM products over 5 generations of technology

Addressing needs of Tier-1 customers in stable and growing markets from Data Centers to Industrial & IoT Edge Devices

Strong IP portfolio of over 650 patents and applications generating licensing and royalty revenue

Solid track record of revenue growth, strong margins and cost control building increasing financial stability

Solid Toggle MRAM customer base with growing design wins and growing market opportunity for STT-MRAM with large potential

Leadership Team with experience commercializing technology in our target markets





Appendix

Foundry Partnerships To Supply The Growing Demand



Strong Partnership with GF for STT-MRAM

- 40nm 256Mb discrete chip mass production
- 28nm 1Gb discrete chip ramping mass production
- 22nm FDX embedded for GF SOC customers
- Extended JDA for 12nm MRAM development

Solid Supply Chain for Toggle MRAM

Long-term Chandler manufacturing operation continues



Established manufacturing partnerships for long term growth



5 Global Operation Sites & 8 Regional Offices



